

Operation And Modeling Of The Mos Transistor

4th Ed

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Matching Properties of Deep Sub-Micron MOS Transistors
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Charge-Based MOS Transistor Modeling
The MOS Transistor
Operation and Modeling of the MOS Transistor, Solution Manual
Silicon Integrated Circuits: Physics of the MOS transistor
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Mathematical model of the MOS transistor subjected to high energy radiation
Instructor's Solution Manual for Operation and Modeling of the Mo 3rd Ed
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Charge-Based MOS Transistor Modeling
MOS Transistor Modeling and Characterization for Circuit Simulation
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the mos metal oxide semiconductor transistor is the most important building block of modern silicon integrated circuits this book fills an important gap in the literature by presenting a unified treatment of the operation and modeling of the mos transistor that is complemented with extensive intuitive discussions the mos transistor is the dominant vlsi very large scale integration device and understanding of this device is mandatory for those people planning a career in device physics and modeling as well as in circuit design especially important for university courses there is a logical systematic and progressive description that starts with semiconductor fundamentals and builds up to a comprehensive understanding of the basics of mos transistors for practicing professionals there are details of nuances observed in mos transistor behavior and various approaches to modeling these are presented detailed derivations are given for modeling dc currents charges for large signal operation small signal operation at low frequencies and high frequencies and noise

matching properties of deep sub micron mos transistors examines this interesting phenomenon microscopic fluctuations cause stochastic parameter fluctuations that affect the accuracy of the mosfet for analog circuits this determines the trade off between speed power accuracy and yield furthermore due to the down scaling of device dimensions transistor mismatch has an increasing impact on digital circuits the matching properties of mosfets are studied at several levels of abstraction a simple and physics based model is presented that accurately describes the mismatch in the drain current the model is illustrated by dimensioning the unit current cell of a current steering d a converter the most commonly used methods to extract the matching properties of a technology are bench marked with respect to model accuracy measurement accuracy and speed and physical contents of the extracted parameters the physical origins of microscopic fluctuations and how they affect mosfet operation are investigated this leads to a refinement of the generally applied 1 area law in addition the analysis of simple transistor models highlights the physical mechanisms that dominate the fluctuations in the drain current and transconductance the impact of process parameters on the matching properties is discussed the impact of gate line edge roughness is investigated which is considered to be one of the roadblocks to the further down scaling of the mos transistor matching properties of deep sub micron mos transistors is aimed at device physicists characterization engineers technology designers circuit designers or anybody else interested in the stochastic properties of the mosfet

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modern large scale analog integrated circuits ics are essentially composed of metal oxide semiconductor mos transistors and their interconnections as technology scales down to deep sub micron dimensions and supply voltage decreases to reduce power consumption these complex analog circuits are even more dependent on the exact behavior of each transistor high performance analog circuit design requires a very detailed model of the transistor describing accurately its static and dynamic behaviors its noise and matching limitations and its temperature variations the charge based ekv enz krummenacher vittoz mos transistor model for ic design has been developed to provide a clear understanding of the device properties without the use of complicated equations all the static dynamic noise non quasi static models are completely described in terms of the inversion charge at the source and at the drain taking advantage of the symmetry of the device thanks to its hierarchical structure the model offers several coherent description levels from basic hand calculation equations to complete computer simulation model it is also compact with a minimum number of process dependant device parameters written by its developers this book provides a comprehensive treatment of the ekv charge based model of the mos transistor for the design and simulation of low power analog and rf ics clearly split into three parts the authors systematically examine the basic long channel intrinsic charge based model including all the fundamental aspects of the ekv most model such as the basic large signal static model the noise model and a discussion of temperature effects and matching properties the extended charge based model presenting important information for understanding the operation of deep submicron devices the high frequency model setting out a complete mos transistor model required for designing rf cmos integrated circuits practising engineers and circuit designers in the semiconductor device and electronics systems industry will find this book a valuable guide to the modelling of mos transistors for integrated circuits it is also a useful reference for advanced students in electrical and computer engineering

operation and modeling of the mos transistor has become a standard in academia and industry extensively revised and updated the third edition of this highly acclaimed text provides a thorough treatment of the mos transistor the key element of modern microelectronic chips

this volume provides a timely description of the latest compact mos transistor models for circuit simulation the first generation bsim3 and bsim4 models that have dominated circuit

simulation in the last decade are no longer capable of characterizing all the important features of modern sub 100nm mos transistors this book discusses the second generation mos transistor models that are now in urgent demand and being brought into the initial phase of manufacturing applications it considers how the models are to include the complete drift diffusion theory using the surface potential variable in the mos transistor channel in order to give one characterization equation

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